

# Silicon Photomultipliers (SiPM), Low-Noise, Blue-Sensitive

## C-Series SiPM Sensors

The C-Series low-light sensors from onsemi feature an industry-leading low dark-count rate combined with a high PDE. For ultrafast timing applications, C-Series sensors have a fast output that can have a rise time of 300 ps and a pulse width of 600 ps. The C-Series is available in different sensor sizes (1 mm, 3 mm and 6 mm) and packaged in a 4-side tileable surface mount (SMT) package that is compatible with industry standard, lead-free, reflow soldering processes.

The C-Series Silicon Photomultipliers (SiPM) form a range of high gain, single-photon sensitive, UV-to-visible light sensors. They have performance characteristics similar to a conventional PMT, while benefiting from the practical advantages of solid-state technology: low operating voltage, excellent temperature stability, robustness, compactness, output uniformity, and low cost. For advice on the usage of these sensors please refer to the [Biasing and Readout](#) Application Note.

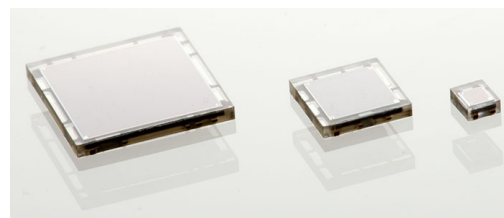


Figure 1. C-Series Sensors

### ORDERING INFORMATION

See detailed ordering and shipping information on page 14 of this data sheet.

Table 1. PERFORMANCE PARAMETERS

| Sensor Size | Microcell Size                 | Parameter (Note 1)                                         | Overvoltage | Min. | Typ. | Max. | Units |
|-------------|--------------------------------|------------------------------------------------------------|-------------|------|------|------|-------|
| 1 mm        | 10 $\mu$ , 20 $\mu$ , 35 $\mu$ | Breakdown Voltage (Vbr) (Note 3)                           |             | 24.2 |      | 24.7 | V     |
| 3 mm        | 20 $\mu$ , 35 $\mu$ , 50 $\mu$ |                                                            |             |      |      |      |       |
| 6 mm        | 35 $\mu$                       |                                                            |             |      |      |      |       |
| 1 mm        | 10 $\mu$ , 20 $\mu$ , 35 $\mu$ | Recommended overvoltage Range (Voltage above Vbr) (Note 2) |             | 1.0  |      | 5.0  | V     |
| 3 mm        | 20 $\mu$ , 35 $\mu$ , 50 $\mu$ |                                                            |             |      |      |      |       |
| 6 mm        | 35 $\mu$                       |                                                            |             |      |      |      |       |
| 1 mm        | 10 $\mu$ , 20 $\mu$ , 35 $\mu$ | Spectral Range (Note 4)                                    |             | 300  |      | 950  | nm    |
| 3 mm        | 20 $\mu$ , 35 $\mu$ , 50 $\mu$ |                                                            |             |      |      |      |       |
| 6 mm        | 35 $\mu$                       |                                                            |             |      |      |      |       |
| 1 mm        | 10 $\mu$ , 20 $\mu$ , 35 $\mu$ | Peak Wavelength ( $\lambda_p$ )                            |             |      | 420  |      | nm    |
| 3 mm        | 20 $\mu$ , 35 $\mu$ , 50 $\mu$ |                                                            |             |      |      |      |       |
| 6 mm        | 35 $\mu$                       |                                                            |             |      |      |      |       |

## C-Series SiPM Sensors

Table 1. PERFORMANCE PARAMETERS (continued)

| Sensor Size | Microcell Size | Parameter (Note 1)                 | Overvoltage | Min.            | Typ. | Max. | Units |
|-------------|----------------|------------------------------------|-------------|-----------------|------|------|-------|
| 1 mm        | 10 $\mu$       | PDE (Note 5) at $\lambda_p$        | Vbr + 2.5 V | 14              |      |      | %     |
|             | 20 $\mu$       |                                    |             | 24              |      |      | %     |
|             | 35 $\mu$       |                                    |             | 31              |      |      | %     |
| 1 mm        | 10 $\mu$       |                                    | Vbr + 5.0 V | 18              |      |      | %     |
|             | 20 $\mu$       |                                    |             | 31              |      |      | %     |
|             | 35 $\mu$       |                                    |             | 41              |      |      | %     |
| 3 mm        | 20 $\mu$       |                                    | Vbr + 2.5 V | 24              |      |      | %     |
|             | 35 $\mu$       |                                    |             | 31              |      |      | %     |
|             | 50 $\mu$       |                                    |             | 35              |      |      | %     |
| 3 mm        | 20 $\mu$       |                                    | Vbr + 5.0 V | 31              |      |      | %     |
|             | 35 $\mu$       |                                    |             | 41              |      |      | %     |
|             | 50 $\mu$       |                                    |             | 47              |      |      | %     |
| 6 mm        | 35 $\mu$       |                                    | Vbr + 2.5 V | 31              |      |      | %     |
| 6 mm        | 35 $\mu$       |                                    | Vbr + 5.0 V | 41              |      |      | %     |
| 1 mm        | 10 $\mu$       | Gain<br>(anode to cathode readout) | Vbr + 2.5 V | $2 \times 10^5$ |      |      |       |
|             | 20 $\mu$       |                                    |             | $1 \times 10^6$ |      |      |       |
|             | 35 $\mu$       |                                    |             | $3 \times 10^6$ |      |      |       |
| 3 mm        | 20 $\mu$       |                                    |             | $1 \times 10^6$ |      |      |       |
|             | 35 $\mu$       |                                    |             | $3 \times 10^6$ |      |      |       |
|             | 50 $\mu$       |                                    |             | $6 \times 10^6$ |      |      |       |
| 6 mm        | 35 $\mu$       |                                    |             | $3 \times 10^6$ |      |      |       |
| 1 mm        | 10 $\mu$       | Dark Current (Note 6)              | Vbr + 2.5 V |                 | 1    | 3    | nA    |
|             | 20 $\mu$       |                                    |             |                 | 5    | 16   | nA    |
|             | 35 $\mu$       |                                    |             |                 | 15   | 49   | nA    |
| 3 mm        | 20 $\mu$       |                                    |             |                 | 50   | 142  | nA    |
|             | 35 $\mu$       |                                    |             |                 | 154  | 443  | nA    |
|             | 50 $\mu$       |                                    |             |                 | 319  | 914  | nA    |
| 6 mm        | 35 $\mu$       |                                    |             |                 | 618  | 1750 | nA    |

## C-Series SiPM Sensors

**Table 1. PERFORMANCE PARAMETERS** (continued)

| Sensor Size | Microcell Size                 | Parameter (Note 1)                                 | Overvoltage | Min. | Typ. | Max. | Units |
|-------------|--------------------------------|----------------------------------------------------|-------------|------|------|------|-------|
| 1 mm        | 10 $\mu$                       | Dark Count Rate                                    | Vbr + 2.5 V |      | 30   | 96   | kHz   |
|             | 20 $\mu$                       |                                                    |             |      | 30   | 96   | kHz   |
|             | 35 $\mu$                       |                                                    |             |      | 30   | 96   | kHz   |
| 3 mm        | 20 $\mu$                       |                                                    |             |      | 300  | 860  | kHz   |
|             | 35 $\mu$                       |                                                    |             |      | 300  | 860  | kHz   |
|             | 50 $\mu$                       |                                                    |             |      | 300  | 860  | kHz   |
| 6 mm        | 35 $\mu$                       |                                                    |             |      | 1200 | 3400 | kHz   |
| 1 mm        | 10 $\mu$ , 20 $\mu$ , 35 $\mu$ | Rise Time – Fast Output (Note 7)                   |             | 0.3  |      |      | ns    |
| 3 mm        | 20 $\mu$ , 35 $\mu$ , 50 $\mu$ |                                                    |             | 0.6  |      |      | ns    |
| 6 mm        | 35 $\mu$                       |                                                    |             | 1.0  |      |      | ns    |
| 1 mm        | 10 $\mu$ , 20 $\mu$ , 35 $\mu$ | Signal Pulse Width – Fast Output (FWHM)            |             | 0.6  |      |      | ns    |
| 3 mm        | 20 $\mu$ , 35 $\mu$ , 50 $\mu$ |                                                    |             | 1.5  |      |      | ns    |
| 6 mm        | 35 $\mu$                       |                                                    |             | 3.2  |      |      | ns    |
| 1 mm        | 10 $\mu$                       | Microcell recharge time constant (Note 8)          |             | 5    |      |      | ns    |
|             | 20 $\mu$                       |                                                    |             | 23   |      |      | ns    |
|             | 35 $\mu$                       |                                                    |             | 82   |      |      | ns    |
| 3 mm        | 20 $\mu$                       |                                                    |             | 23   |      |      | ns    |
|             | 35 $\mu$                       |                                                    |             | 82   |      |      | ns    |
|             | 50 $\mu$                       |                                                    |             | 159  |      |      | ns    |
| 6 mm        | 35 $\mu$                       |                                                    |             | 95   |      |      | ns    |
| 1 mm        | 10 $\mu$                       | Capacitance (Note 9)<br>(anode–cathode)            | Vbr + 2.5 V | 50   |      |      | pF    |
|             | 20 $\mu$                       |                                                    |             | 90   |      |      | pF    |
|             | 35 $\mu$                       |                                                    |             | 100  |      |      | pF    |
| 3 mm        | 20 $\mu$                       |                                                    |             | 770  |      |      | pF    |
|             | 35 $\mu$                       |                                                    |             | 850  |      |      | pF    |
|             | 50 $\mu$                       |                                                    |             | 920  |      |      | pF    |
| 6 mm        | 35 $\mu$                       |                                                    |             | 3400 |      |      | pF    |
| 1 mm        | 10 $\mu$                       | Capacitance (Note 9)<br>(fast terminal to cathode) | Vbr + 2.5 V | 1    |      |      | pF    |
|             | 20 $\mu$                       |                                                    |             | 1    |      |      | pF    |
|             | 35 $\mu$                       |                                                    |             | 1    |      |      | pF    |

## C-Series SiPM Sensors

**Table 1. PERFORMANCE PARAMETERS** (continued)

| Sensor Size | Microcell Size | Parameter (Note 1)                                 | Overvoltage | Min. | Typ. | Max.   | Units |
|-------------|----------------|----------------------------------------------------|-------------|------|------|--------|-------|
| 3 mm        | 20μ            | Capacitance (Note 9)<br>(fast terminal to cathode) | Vbr + 2.5 V | 20   |      | pF     |       |
|             | 35μ            |                                                    |             | 12   |      | pF     |       |
|             | 50μ            |                                                    |             | 7    |      | pF     |       |
| 6 mm        | 35μ            |                                                    |             | 48   |      | pF     |       |
| 1 mm        | 10μ, 20μ, 35μ  | Temperature dependence of Vbr                      |             | 21.5 |      | mV/°C  |       |
| 3 mm        | 20μ, 35μ, 50μ  |                                                    |             |      |      |        |       |
| 6 mm        | 35μ            |                                                    |             |      |      |        |       |
| 1 mm        | 10μ, 20μ, 35μ  | Temperature dependence of Gain (Note 10)           |             | −0.8 |      | % / °C |       |
| 3 mm        | 20μ, 35μ, 50μ  |                                                    |             |      |      |        |       |
| 6 mm        | 35μ            |                                                    |             |      |      |        |       |
| 1 mm        | 10μ            | Crosstalk                                          | Vbr + 2.5 V | 0.6  |      | %      |       |
|             | 20μ            |                                                    |             | 3    |      | %      |       |
|             | 35μ            |                                                    |             | 7    |      | %      |       |
| 3 mm        | 20μ            |                                                    |             | 3    |      | %      |       |
|             | 35μ            |                                                    |             | 7    |      | %      |       |
|             | 50μ            |                                                    |             | 10   |      | %      |       |
| 6 mm        | 35μ            |                                                    |             | 7    |      | %      |       |
| 1 mm        | 10μ            | Afterpulsing                                       | Vbr + 2.5 V | 0.2  |      | %      |       |
|             | 20μ            |                                                    |             | 0.2  |      | %      |       |
|             | 35μ            |                                                    |             | 0.2  |      | %      |       |
| 3 mm        | 20μ            |                                                    |             | 0.2  |      | %      |       |
|             | 35μ            |                                                    |             | 0.2  |      | %      |       |
|             | 50μ            |                                                    |             | 0.6  |      | %      |       |
| 6 mm        | 35μ            |                                                    |             | 0.2  |      | %      |       |

1. All measurements made at 2.5 V overvoltage and 21°C unless otherwise stated.
2. Please consult the maximum current levels on page 6 when selecting the overvoltage to apply.
3. The breakdown voltage (Vbr) is defined as the value of the voltage intercept of a straight line fit to a plot of  $\sqrt{I}$  vs V, where I is the current and V is the bias voltage.
4. The range where PDE > 1% at Vbr + 5.0 V.
5. Note that the PDE does not contain contributions from afterpulsing or crosstalk.
6. Dark current derived from dark count data as  $DC \times M \times q \times (1 + CT)$ , where DC is dark count, M is gain, q is the charge of an electron, and CT is cross talk.
7. Measured as time to go from 10% to 90% of the peak amplitude.
8. RC charging time constant of the microcell ( $\tau$ )
9. Internal capacitance of the sensor. Typically add 2–3 pF for sensor in package. Listed by unique microcell size for each part version.
10. Quoted as the percentage change per degree C from the measured value at 21°C.

## C-Series SiPM Sensors

### GENERAL PARAMETERS

**Table 2. GENERAL PARAMETERS**

|                       | 1 mm                                     | 3 mm                                       | 6 mm                  |
|-----------------------|------------------------------------------|--------------------------------------------|-----------------------|
|                       | 10010, 10020, 10035                      | 30020, 30035, 30050                        | 60035                 |
| Active area           | 1 × 1 mm <sup>2</sup>                    | 3 × 3 mm <sup>2</sup>                      | 6 × 6 mm <sup>2</sup> |
| No. of microcells     | 10010: 2880<br>10020: 1296<br>10035: 504 | 30020: 10998<br>30035: 4774<br>30050: 2668 | 60035: 18980          |
| Microcell fill factor | 10010: 28%<br>10020: 48%<br>10035: 64%   | 30020: 48%<br>30035: 64%<br>30050: 72%     | 60035: 64%            |

**Table 3. PACKAGE PARAMETERS**

|                                         | 1 mm                                                                                                                                                                               | 3 mm                  | 6 mm                  |
|-----------------------------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-----------------------|-----------------------|
|                                         | 10010, 10020, 10035                                                                                                                                                                | 30020, 30035, 30050   | 60035                 |
| Package dimensions                      | 1.5 × 1.8 mm <sup>2</sup>                                                                                                                                                          | 4 × 4 mm <sup>2</sup> | 7 × 7 mm <sup>2</sup> |
| Recommended operating temperature range | -40°C to +85°C                                                                                                                                                                     |                       |                       |
| Maximum storage temperature             | +105°C                                                                                                                                                                             |                       |                       |
| Soldering conditions                    | Lead-free, reflow soldering process compatible<br>(MSL 3 for tape & reel quantities; MSL 4 for tape only qty.)<br>See the <a href="#">SMT Handling Tech Note</a> for more details. |                       |                       |
| Encapsulant type                        | Clear transfer molding compound                                                                                                                                                    |                       |                       |
| Encapsulant refractive Index            | 1.59 @ 420 nm                                                                                                                                                                      |                       |                       |

**Table 4. MAXIMUM CURRENT LEVELS FOR EACH SENSOR SIZE**

| 1 mm                | 3 mm                | 6 mm  |
|---------------------|---------------------|-------|
| 10010, 10020, 10035 | 30020, 30035, 30050 | 60035 |
| 6 mA                | 15 mA               | 20 mA |

## C-Series SiPM Sensors

### CIRCUIT SCHEMATICS

An SiPM is formed of a large number (hundreds or thousands) of microcells. Each microcell is an avalanche photodiode with its own quench resistor and a capacitively coupled fast output. These microcells are arranged in

a close-packed array with all of the like terminals (e.g. all of the anodes) summed together. The array of microcells can thus be considered as a single photodiode sensor with three terminals: anode, cathode and fast output.

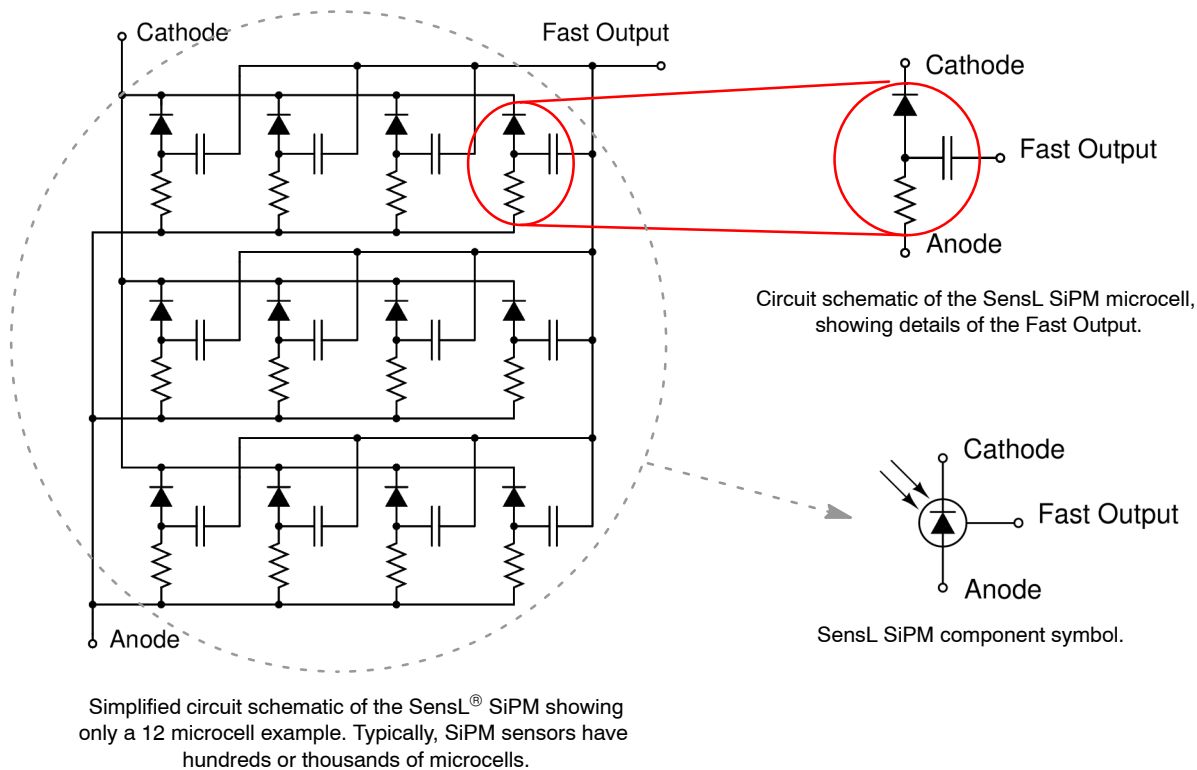


**Figure 2. Circuit Schematic**

# C-Series SiPM Sensors

## PERFORMANCE

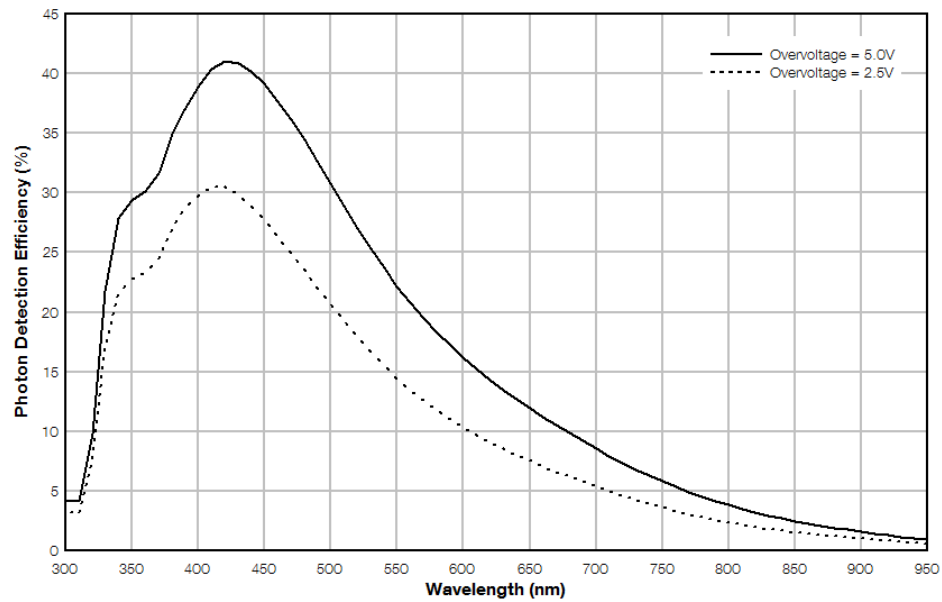


**Figure 3. PDE versus Wavelength**  
(MicroFC-30035-SMT)

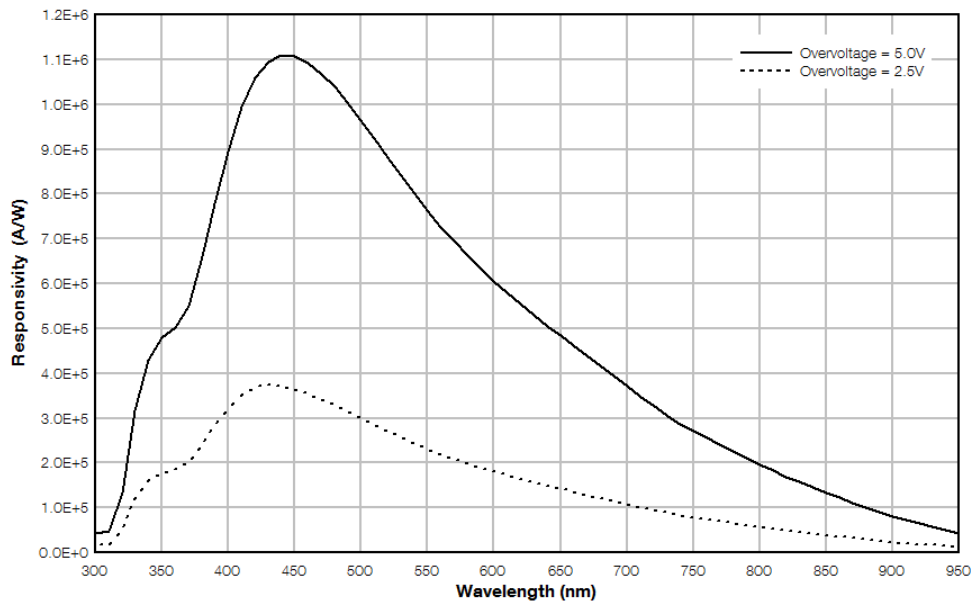


**Figure 4. Responsivity versus Wavelength**  
(MicroFC-30035-SMT)

## C-Series SiPM Sensors

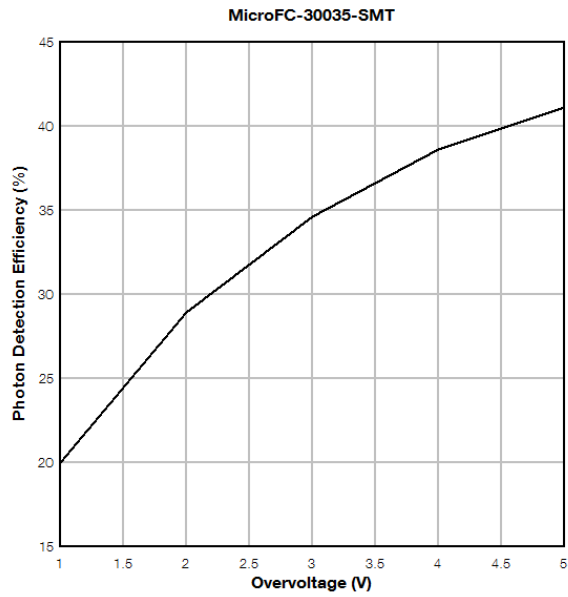


Figure 5. PDE at 420 nm versus Voltage

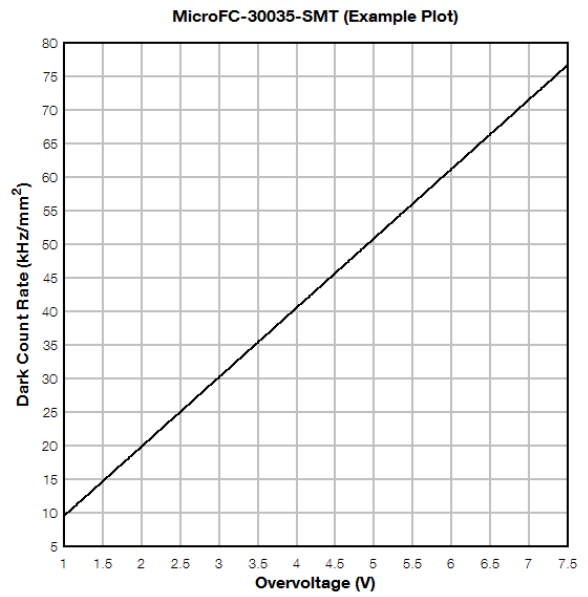


Figure 6. Dark Count Rate versus Overvoltage

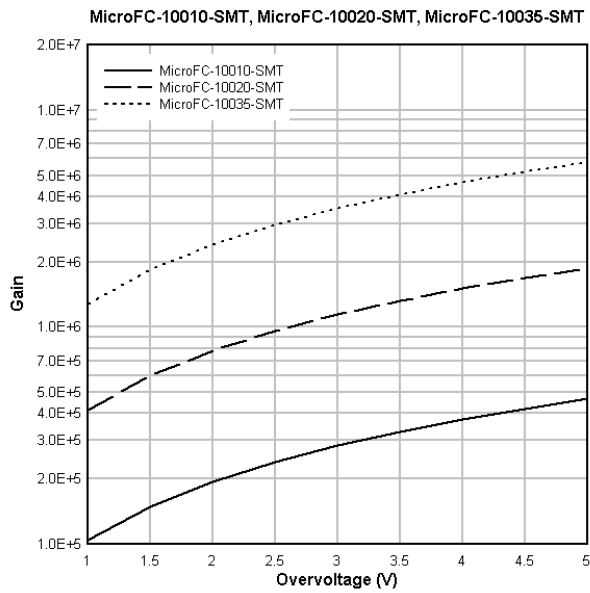


Figure 7. Gain versus Overvoltage

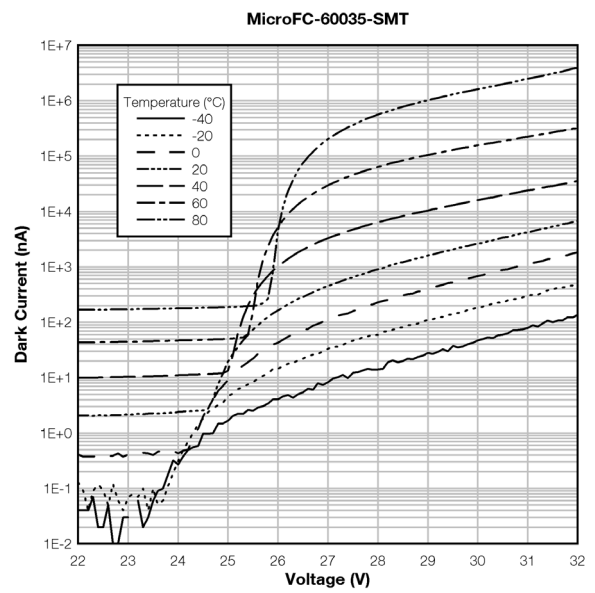


Figure 8. Dark Current versus Voltage and Temperature

## C-Series SiPM Sensors

### EVALUATION BOARD OPTIONS

#### SMA Biasing Board (MicroFC-SMA-XXXXX)

The MicroFC-SMA is a printed circuit board (PCB) that can facilitate the evaluation of the C-Series SMT sensors. The board has three female SMA connectors for connecting the bias voltage, the standard output from the anode and the fast output signal. The output signals can be connected directly to a 50  $\Omega$ -terminated oscilloscope for viewing. The biasing and output signal tracks are laid out in such a way as to preserve the fast timing characteristics of the sensor.

The MicroFC-SMA is recommended for users who require a plug-and-play set-up to quickly evaluate C-Series SMT sensors with optimum timing performance. The board also allows the standard output from the anode-cathode readout to be observed at the same time as the fast output. The outputs can be connected directly to the oscilloscope or measurement device, but external preamplification may be required to boost the signal. The table below lists the SMA board connections. The SMA board electrical schematics are available to download in [AND9809/D](#).

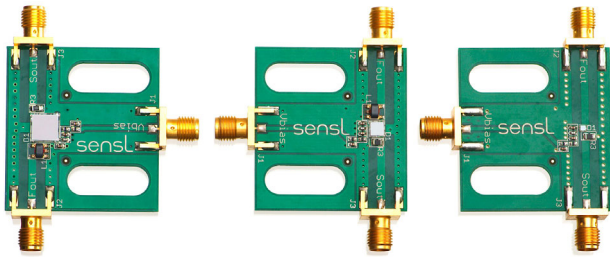


Figure 9. SMA Biasing Board

| MicroFC-SMA-XXXXX |                               |
|-------------------|-------------------------------|
| Output            | Function                      |
| Vbias             | Positive bias input (cathode) |
| Fout              | Fast output                   |
| Sout              | Standard output (anode)       |

#### Pin Adapter (MicroFC-SMTPA-XXXXX)

The SMT Pin Adapter board (SMTPA) is a small PCB board that houses the SMT sensor and has through-hole pins to allow for use with standard sockets or probe clips. This product is useful for those needing a quick way to evaluate the C-Series SMT sensors without the need for specialist surface-mount soldering. While this is a 'quick fix' suitable for many evaluations, it should be noted that the timing performance from this board will not be optimized and if the best possible timing performance is required, the MicroFC-SMA-XXXXX is recommended. The pin-out

information is shown in the table below. The SMTPA board electrical schematics are shown in Figure 12 and are available to download in [AND9809/D](#).



Figure 10. Pin Adapter

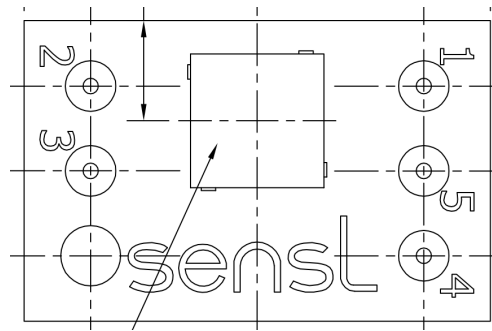


Figure 11. MicroFC-SMTPA-XXXXX

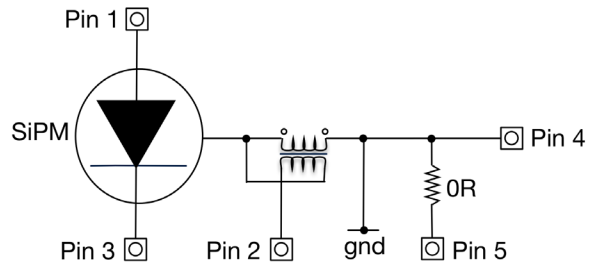


Figure 12. SMTPA Board Circuit Schematic

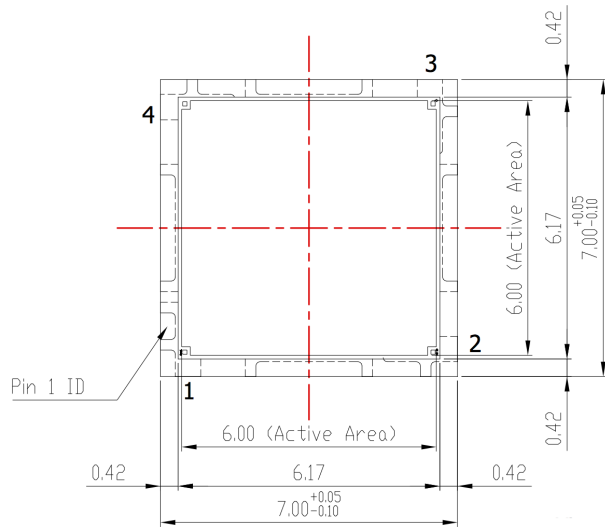
| MicroFC-SMTPA-XXXXX |             |
|---------------------|-------------|
| Pin No.             | Connection  |
| 1                   | Anode       |
| 2                   | Fast output |
| 3                   | Cathode     |
| 4                   | Ground      |
| 5                   | No connect  |

# C-Series SiPM Sensors

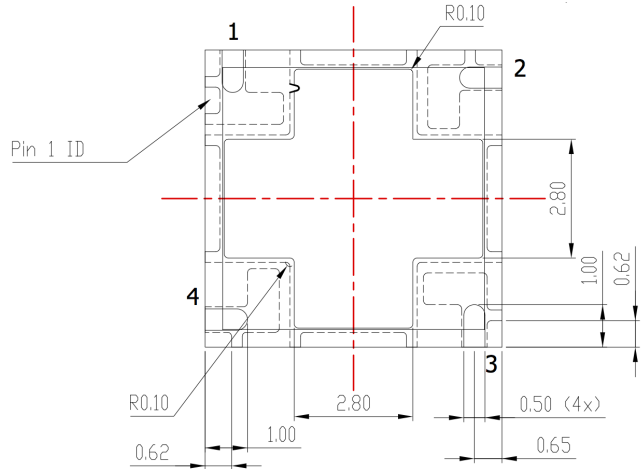
## PACKAGE DIMENSIONS

(All Dimensions in mm)

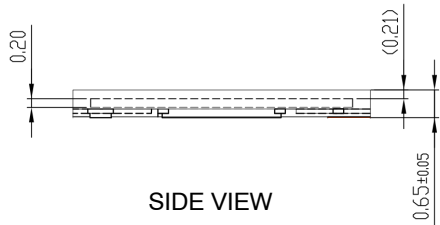
### MicroFC-60035-SMT



TOP VIEW



BOTTOM VIEW



SIDE VIEW

| Pin Assignments |                   |
|-----------------|-------------------|
| Pin #           | MicroFC-60035-SMT |
| 1               | Anode             |
| 2               | Fast Output       |
| 3               | Cathode           |
| 4, 5            | No Connect*       |

\*The 'No Connect' pin 4 should be soldered to the PCB. This pin can be connected to ground but it can also be left floating without affecting the dark noise. It is recommended that the Pin 5 paddle is NOT soldered to the PCB and is left floating to achieve optimal soldering on pins 1 to 4. Please note the full advice in the CAD file.

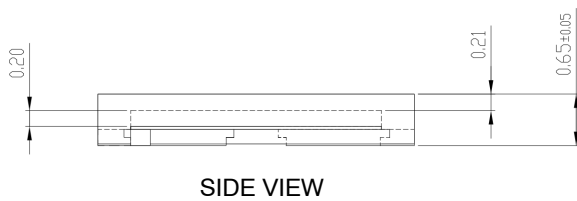
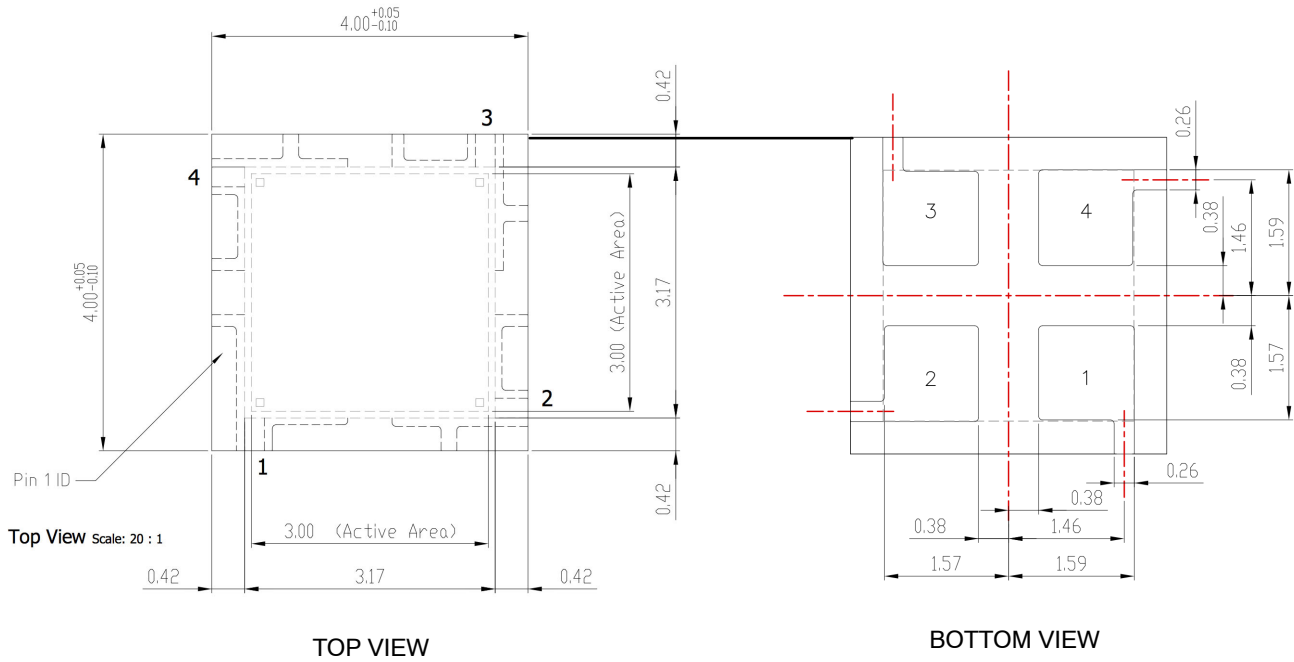
The complete MicroFC-60035-SMT POD is available to download [here](#).

# C-Series SiPM Sensors

## PACKAGE DIMENSIONS

(All Dimensions in mm)

MicroFC-30020-SMT, MicroFC-30035-SMT, MicroFC-30050-SMT



| Pin Assignments |                   |
|-----------------|-------------------|
| Pin #           | MicroFC-300XX-SMT |
| 1               | Anode             |
| 2               | Fast Output       |
| 3               | Cathode           |
| 4               | No Connect*       |

\*The 'No Connect' pin 4 should be soldered to the PCB. It can be connected to ground but it can also be left floating without affecting the dark noise.

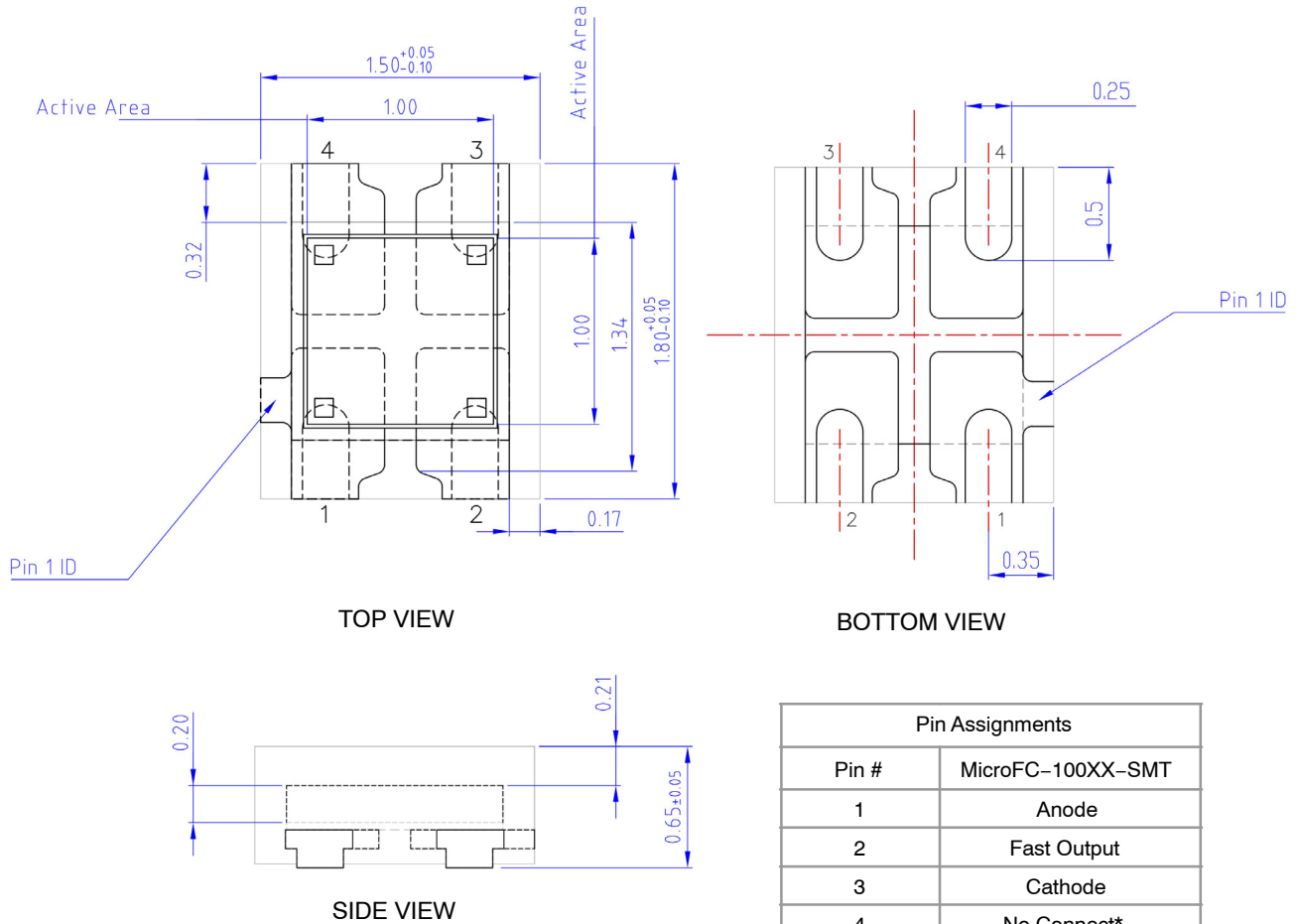
The complete MicroFC-300xx-SMT POD is available to download [here](#).

# C-Series SiPM Sensors

## PACKAGE DIMENSIONS

(All Dimensions in mm)

MicroFC-10010-SMT, MicroFC-10020-SMT & MicroFC-10035-SMT



\*The 'No Connect' pin 4 should be soldered to the PCB. It can be connected to ground but it can also be left floating without affecting the dark noise.

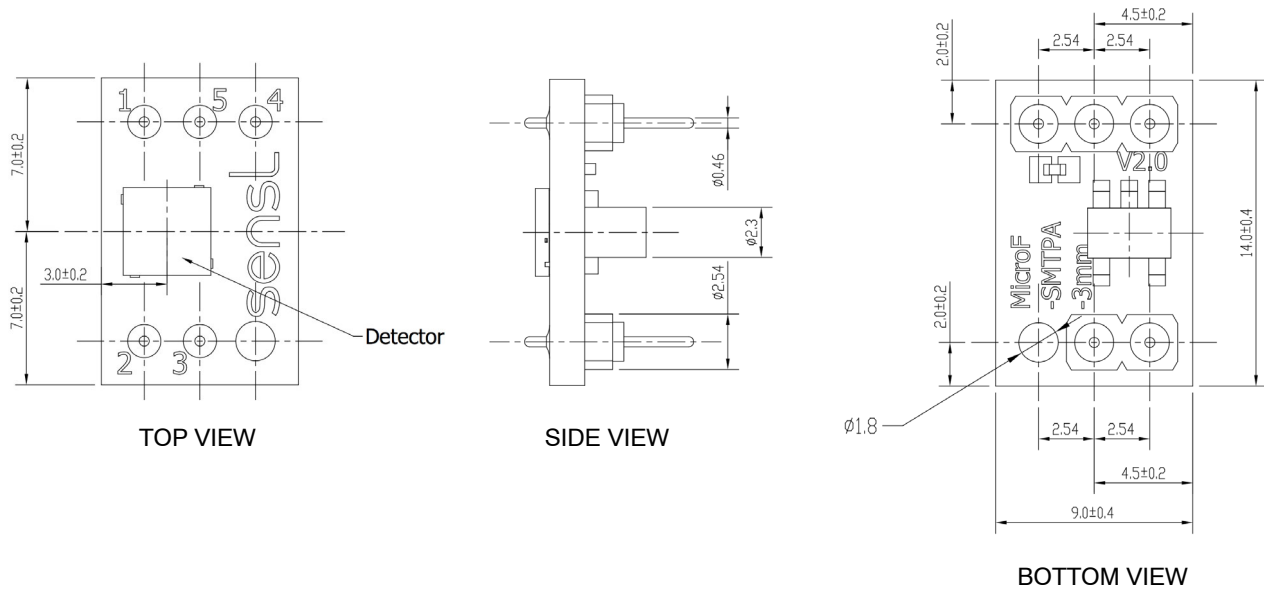
The complete MicroFC-100XX-SMT POD is available to download [here](#).

## C-Series SiPM Sensors

### PACKAGE DIMENSIONS

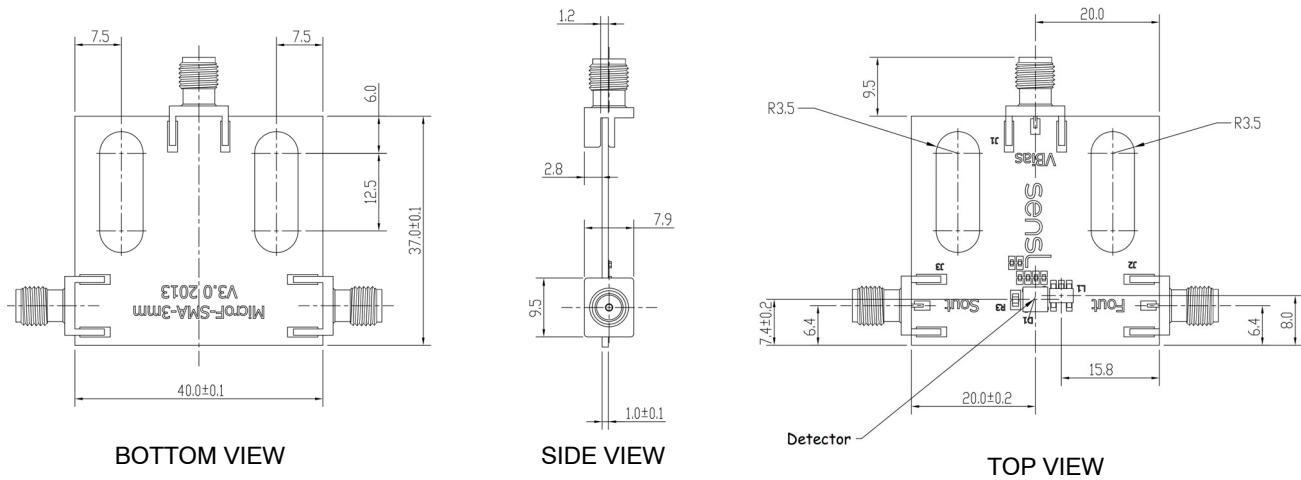
(All Dimensions in mm)

#### MicroFC-SMTPA Board



The electrical schematics for the SMTPA board is available in [AND9809/D](#).

#### MicroFC-SMA Board



The electrical schematics for the SMA board is available in [AND9809/D](#).

## C-Series SiPM Sensors

### USEFUL LINKS

- [Introduction to Silicon Photomultipliers Application Note](#) – If you are new to SiPM, this document explains their operation and main performance parameters.
- [Biasing and Readout Application Note](#) – This document gives detailed information on how to bias the sensor for both standard and fast configurations, and amplifying and reading out the signal.
- [How to Evaluate and Compare Silicon Photomultipliers Application Note](#) – Information on what to consider when selecting an SiPM.
- [Handling and Soldering Guide](#) – This document gives information on safe handling of the sensors and soldering to PCB.

### ORDERING INFORMATION

**Table 5. ORDERING INFORMATION**

| Product Code<br>(Note 11) | Microcell Size<br>(Total Number) | Sensor<br>Active Area | Package Type                                                           | Delivery<br>Options<br>(Note 12) |
|---------------------------|----------------------------------|-----------------------|------------------------------------------------------------------------|----------------------------------|
| 10000 Series              |                                  |                       |                                                                        |                                  |
| MICROFC-10010-SMT         | 10 μm<br>(2880 microcells)       | 1 mm × 1 mm           | 4-side tileable, surface mount package (SMT)                           | TR1, TR                          |
| MICROFC-SMA-10010-GEVB    |                                  |                       | SMT sensor mounted onto a PCB with SMA connectors for bias and output. | PK                               |
| MICROFC-SMTPA-10010-GEVB  |                                  |                       | SMT sensor mounted onto a pin adapter board.                           | PK                               |
| MICROFC-10020-SMT         | 20 μm<br>(1296 microcells)       |                       | 4-side tileable, surface mount package (SMT)                           | TR1, TR                          |
| MICROFC-SMA-10020-GEVB    |                                  |                       | SMT sensor mounted onto a PCB with SMA connectors for bias and output. | PK                               |
| MICROFC-SMTPA-10020-GEVB  |                                  |                       | SMT sensor mounted onto a pin adapter board.                           | PK                               |
| MICROFC-10035-SMT         | 35 μm<br>(504 microcells)        |                       | 4-side tileable, surface mount package (SMT)                           | TR1, TR                          |
| MICROFC-SMA-10035-GEVB    |                                  |                       | SMT sensor mounted onto a PCB with SMA connectors for bias and output. | PK                               |
| MICROFC-SMTPA-10035-GEVB  |                                  |                       | SMT sensor mounted onto a pin adapter board.                           | PK                               |

## C-Series SiPM Sensors

**Table 5. ORDERING INFORMATION** (continued)

| Product Code<br>(Note 11) | Microcell Size<br>(Total Number) | Sensor<br>Active Area | Package Type | Delivery<br>Options<br>(Note 12) |
|---------------------------|----------------------------------|-----------------------|--------------|----------------------------------|
|---------------------------|----------------------------------|-----------------------|--------------|----------------------------------|

### 30000 Series

|                          |                             |             |                                                                        |         |
|--------------------------|-----------------------------|-------------|------------------------------------------------------------------------|---------|
| MICROFC-30020-SMT        | 20 μm<br>(10998 microcells) | 3 mm × 3 mm | 4-side tileable, surface mount package (SMT)                           | TR1, TR |
| MICROFC-SMA-30020-GEVB   |                             |             | SMT sensor mounted onto a PCB with SMA connectors for bias and output. | PK      |
| MICROFC-SMTPA-30020-GEVB |                             |             | SMT sensor mounted onto a pin adapter board                            | PK      |
| MICROFC-30035-SMT        | 35 μm<br>(4774 microcells)  |             | 4-side tileable, surface mount package (SMT)                           | TR1, TR |
| MICROFC-SMA-30035-GEVB   |                             |             | SMT sensor mounted onto a PCB with SMA connectors for bias and output. | PK      |
| MICROFC-SMTPA-30035-GEVB |                             |             | SMT sensor mounted onto a pin adapter board                            | PK      |
| MICROFC-30050-SMT        | 50 μm<br>(2668 microcells)  |             | 4-side tileable, surface mount package (SMT)                           | TR1, TR |
| MICROFC-SMA-30050-GEVB   |                             |             | SMT sensor mounted onto a PCB with SMA connectors for bias and output. | PK      |
| MICROFC-SMTPA-30050-GEVB |                             |             | SMT sensor mounted onto a pin adapter board                            | PK      |

### 60000 Series

|                          |                                        |                  |                                                                        |         |
|--------------------------|----------------------------------------|------------------|------------------------------------------------------------------------|---------|
| MICROFC-60035-SMT        | 35 $\mu\text{m}$<br>(18980 microcells) | 6mm $\times$ 6mm | 4-side tileable, surface mount package (SMT)                           | TR1, TR |
| MICROFC-SMA-60035-GEVB   |                                        |                  | SMT sensor mounted onto a PCB with SMA connectors for bias and output. | PK      |
| MICROFC-SMTPA-60035-GEVB |                                        |                  | SMT sensor mounted onto a pin adapter board                            | PK      |

11. All Devices are Pb-Free and are RoHS Compliant.

12. The two-letter delivery option code should be appended to the order number, e.g.) to receive MICROFC-60035-SMT on tape and reel, use

MICROFC-60035-SMT-TR. The codes are as follows:

PK = ESD Package

TR1 = Tape

TR = Tape and Reel

There is a minimum order quantity (MOQ) of 3000 for the tape and reel (TR) option. The TR option is only available in multiples of the MOQ.

**onsemi**, **Onsemi**, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "**onsemi**" or its affiliates and/or subsidiaries in the United States and/or other countries. **onsemi** owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of **onsemi**'s product/patent coverage may be accessed at [www.onsemi.com/site/pdf/Patent-Marking.pdf](http://www.onsemi.com/site/pdf/Patent-Marking.pdf). **onsemi** reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and **onsemi** makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

## ADDITIONAL INFORMATION

### TECHNICAL PUBLICATIONS:

Technical Library: [www.onsemi.com/design/resources/technical-documentation](http://www.onsemi.com/design/resources/technical-documentation)  
onsemi Website: [www.onsemi.com](http://www.onsemi.com)

### ONLINE SUPPORT: [www.onsemi.com/support](http://www.onsemi.com/support)

For additional information, please contact your local Sales Representative at  
[www.onsemi.com/support/sales](http://www.onsemi.com/support/sales)